# Silicon Carbide Schottky Diode

# 650 V, 4 A

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 25 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = $25^{\circ}$ C unless otherwise noted)

Symbol	Paramete	r	Value	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		650	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)		25	mJ
١ <sub>F</sub>	Continuous Rectified Forward Current @ $T_C < 160^{\circ}C$		4	А
	Continuous Rectified Forward Co	urrent @ T <sub>C</sub> < 135°C	7.6	1
I <sub>F, Max</sub>	Non-Repetitive Peak Forward	$T_C = 25^{\circ}C$ , 10 µs	360	А
	Surge Current	$T_{C} = 150^{\circ}C, 10 \ \mu s$	330	А
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half–Sine Pulse, t <sub>P</sub> = 8.3 ms	38	Α
I <sub>F, RM</sub>	Repetitive Forward Surge Current	Half–Sine Pulse, t <sub>P</sub> = 8.3 ms	18	Α
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	61	W
		$T_{C} = 150^{\circ}C$	10	W
T <sub>J</sub> ,T <sub>STG</sub>	Operating and Storage Temperature Range		–55 to +175	°C

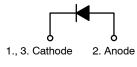
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 25 mJ is based on starting  $T_J = 25^{\circ}C$ ,  $\dot{L} = 0.5$  mH,  $I_{AS} = 10$  A, V = 50 V

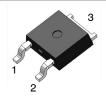


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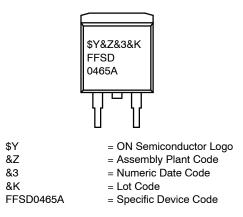


Schottky Diode



DPAK3 (TO-252, 3 LD) CASE 369AS

#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# FFSD0465A

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$			°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	$I_{F} = 4 \text{ A}, T_{C} = 25^{\circ}\text{C}$	-	1.50	1.75	V
		$I_{F} = 4 \text{ A}, T_{C} = 125^{\circ}\text{C}$	-	1.6	2.0	
		I <sub>F</sub> = 4 A, T <sub>C</sub> = 175°C	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	$V_{\rm R}$ = 650 V, $T_{\rm C}$ = 25°C	-	-	200	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	-	400	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	-	600	
$Q_{C}$	Total Capacitive Charge	V = 400 V	-	16	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	258	-	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	29	-	1
		V <sub>R</sub> = 400 V, f = 100 kHz	-	21	-	1

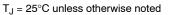
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Part Number	Top Marking	Package	Shipping*	
FFSD0465A	FFSD0465A	DPAK	2500 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

## **TYPICAL CHARACTERISTICS**



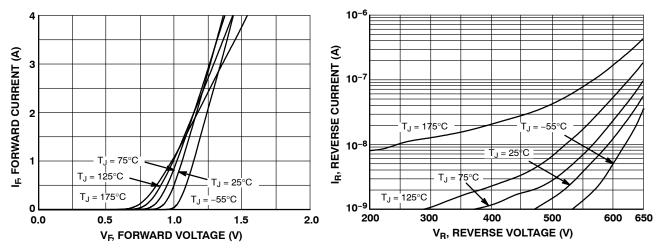


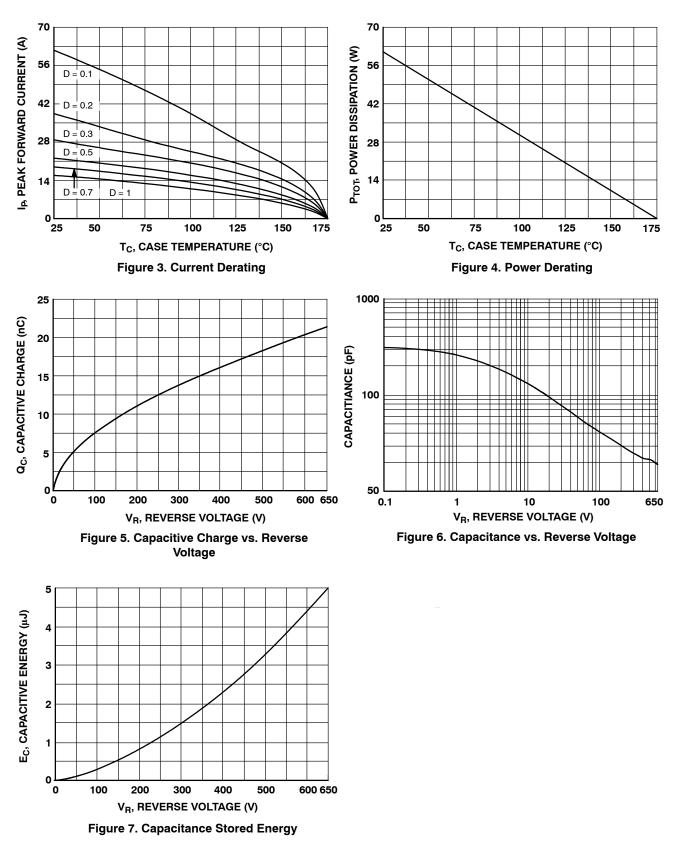


Figure 2. Reverse Characteristics

# FFSD0465A

## TYPICAL CHARACTERISTICS (continued)

 $T_J = 25^{\circ}C$  unless otherwise noted



# FFSD0465A

#### TYPICAL CHARACTERISTICS (continued)

 $T_J = 25^{\circ}C$  unless otherwise noted

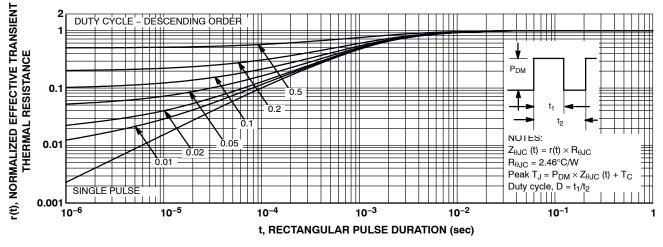


Figure 8. Junction-to-Case Transient Thermal Response Curve

#### **TEST CIRCUIT AND WAVEFORMS**

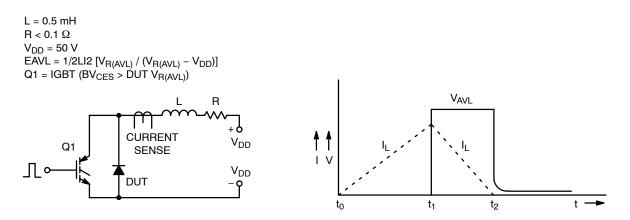
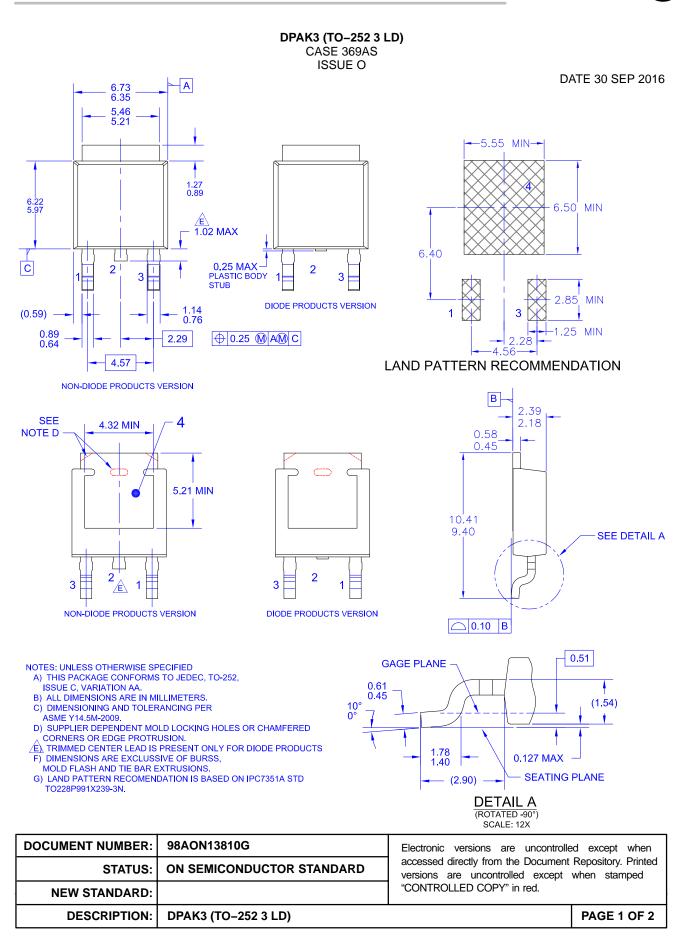


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform







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